VFT2045C

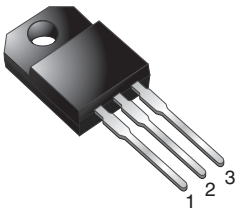
Vishay General Semiconductor

Dual Low-Voltage Trench MOS Barrier Schottky Rectifier

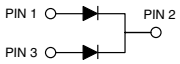
Ultra Low V_F = 0.33 V at I_F = 5.0 A

TMBS®

ITO-220AB



VFT2045C



FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Solder bath temperature 275 °C max. 10 s, per JESD 22-B106
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- **Halogen-free according to IEC 61249-2-21 definition**

RoHS COMPLIANT

HALOGEN FREE

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 10 A
V_{RRM}	45 V
I_{FSM}	160 A
V_F at I_F = 10 A	0.41 V
T_J max.	150 °C

MECHANICAL DATA

Case: ITO-220AB
Molding compound meets UL 94 V-0 flammability rating
Base P/N-M3 - halogen-free, RoHS compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102
M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T_A = 25 °C unless otherwise noted)

PARAMETER		SYMBOL	VFT2045C	UNIT
Maximum repetitive peak reverse voltage		V_{RRM}	45	V
Maximum average forward rectified current (fig. 1)	per device	$I_{F(AV)}$	20	A
	per diode		10	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I_{FSM}	160	A
Isolation voltage from termal to heatsink t = 1 min		V_{AC}	1500	V
Operating junction and storage temperature range		T_J, T_{STG}	- 40 to + 150	°C

For technical questions within your region, please contact one of the following:
DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com

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ELECTRICAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MIN.	UNIT
Instantaneous forward voltage per diode	I_F = 5 A	T_A = 25 °C	V_F (1)	0.44	-	V
	I_F = 10 A			0.49	0.58	
	I_F = 5 A	T_A = 125 °C		0.33	-	
	I_F = 10 A			0.41	0.52	
Reverse current per diode	V_R = 45 V	T_A = 25 °C	I_R (2)	-	2000	µA
		T_A = 125 °C		10	30	mA

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)				
PARAMETER		SYMBOL	VFT2045C	UNIT
Typical thermal resistance	per diode	$R_{\theta JC}$	6.0	°C/W
	per device		4.5	

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
ITO-220AB	VFT2045C-M3/4W	1.76	4W	50/tube	Tube

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

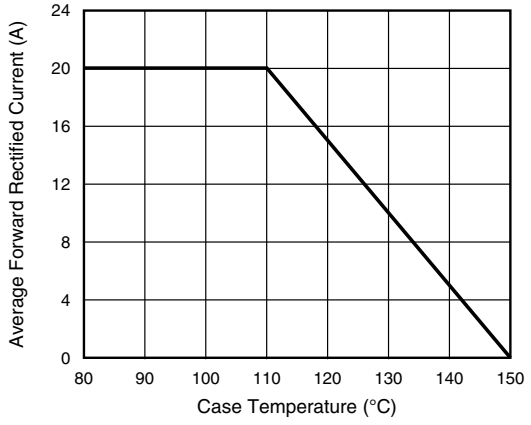

Fig. 1 - Maximum Forward Current Derating Curve

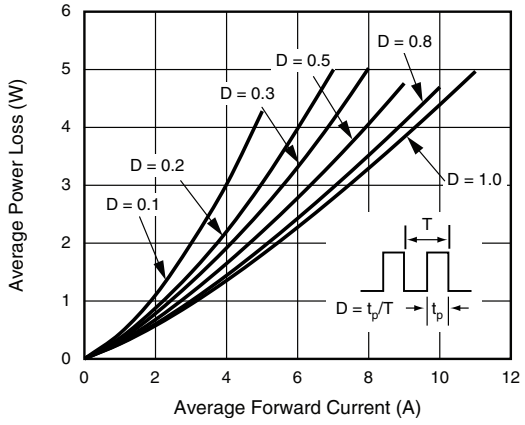

Fig. 2 - Forward Power Loss Characteristics Per Diode

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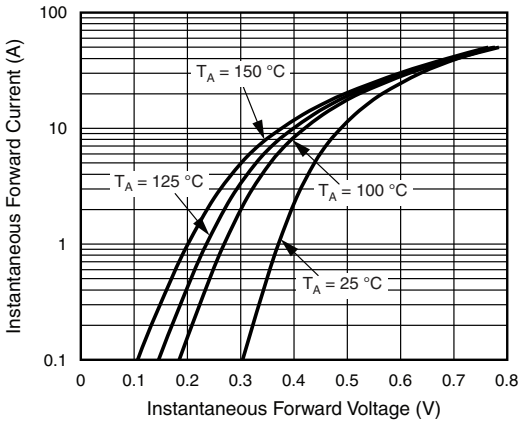


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

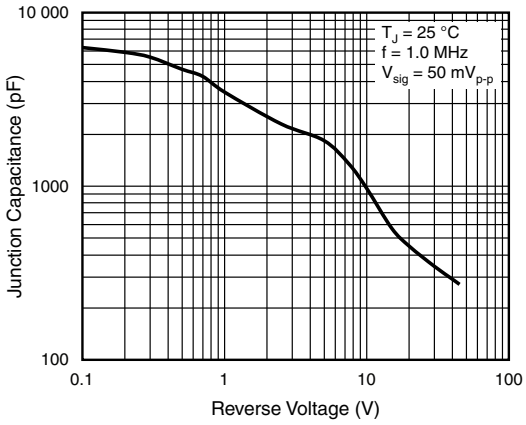


Fig. 5 - Typical Junction Capacitance Per Diode

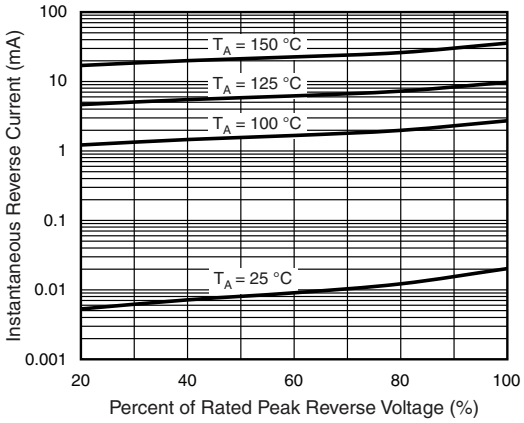


Fig. 4 - Typical Reverse Characteristics Per Diode

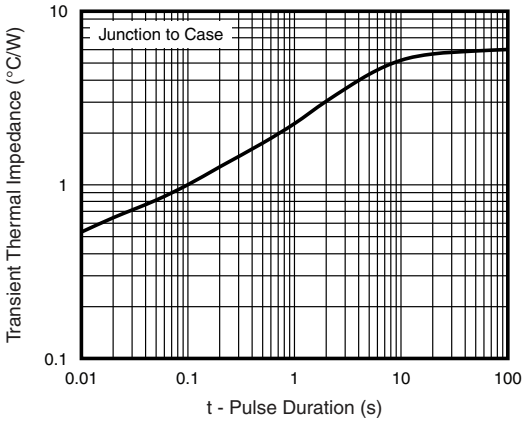
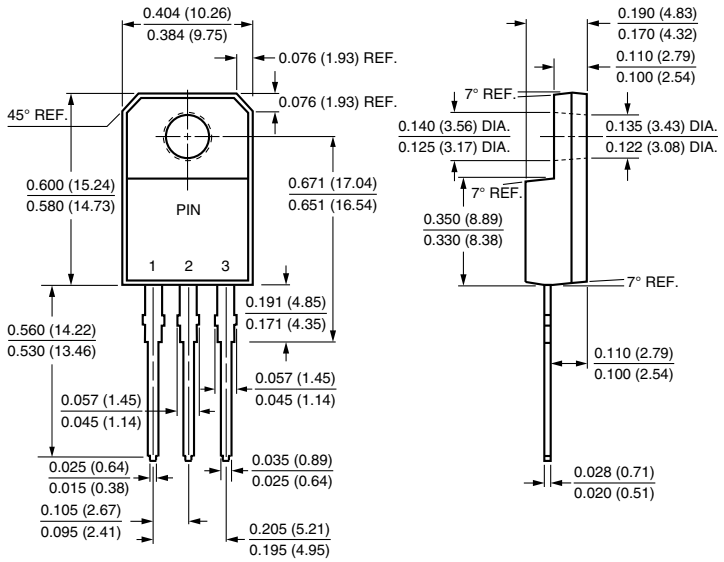


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

ITO-220AB



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